$\begin{array}{|c|c|c|c|c|c|c|c|} \hline & \text{PHIL_BJT } I_S = 57,60122 \text{pA } V_{th} = 26,36066 \text{mV} \\ \hline & \text{SIEMENS } I_S = 29,87850 \text{pA } V_{th} = 26,20057 \text{mV} \\ \hline & \text{modelo propio } I_S = 107,5609 \text{pA } V_{th} = 25,86963 \text{mV} \\ \hline & \text{transistor 1 } I_S = 75,51927 \text{pA } V_{th} = 26,95065 \text{mV} \\ \hline & \text{transistor 2 } I_S = 339,5251 \text{pA } V_{th} = 28,86619 \text{mV} \\ \hline & \text{transistor 3 } I_S = 150,4921 \text{pA } V_{th} = 28,10407 \text{mV} \\ \hline \end{array}$

